

Chapter 5

ELECTRON COLLISION WITH FLUORONITRILES

In this chapter, we provide the findings from our studies on electron-driven molecular events for the fluoronitriles C_3F_5N and C_4F_7N over a large energy range, from the ionization potential to 5000 eV. We use SCOP, CSP-ic and 2P-SEM techniques to estimate elastic and inelastic effects. The research encompasses multiple correlations, predicting dipole polarizability, determining the dielectric constant, and calculating the number density N for these fluoronitriles.

5.1 Introduction

As an insulating gas, sulphur hexafluoride (SF_6) is commonly used in high-voltage devices [1]. Non-toxicity, a low boiling point, and excellent insulating performance are just a few of the many physicochemical features of SF_6 that lead in this direction. However, SF_6 does not decompose very quickly in the atmosphere and has a GWP that is 22,800 times higher than that of carbon dioxide. Thus, finding a suitable alternative to SF_6 has become one of the most critical issues in high-voltage mechatronics. Because of its high reliability, low electromagnetic radiation, SF_6 insulated equipment is widely utilised in high and ultra-high- electricity voltage systems. However, there would be a significant economic loss if insulation on equipment failed. This has also prompted the search for potential SF_6 replacements. The fluoronitrile ($\text{C}_3\text{F}_5\text{N}$ and $\text{C}_4\text{F}_7\text{N}$) gases, have been studied intensively [2–4] in recent years as a potential alternative to SF_6 .

Thus, fluoronitriles have low GWP and high dielectric strength compared to SF_6 , which makes them most suitable alternative to SF_6 in various applications. Table 5.2 compares the dielectric strength and GWP of SF_6 and fluoronitrile gases.

However, there has been comparatively less research into microscopic parameters such the ionisation cross sections (Q_{ion}) upon electron impact. This Q_{ion} is a key variable in the study of electron avalanche and gas breakdown mechanisms [5,6].

Gas electron transport coefficients and discharge reaction rates can be calculated using either Boltzmann's computations or Monte-Carlo calculations [5,6], with Q_{ion} serving as an input. Q_{ion} can be measured experimentally, although not for every gas due to the difficulty of the measurements owing to the molecules' reactivity, Theoretical methods become potent tools for obtaining Q_{ion} , which might be used as a reference in the investigation of the insulating properties of gases. CSP-ic technique [7], Binary-Encounter Bethe (BEB) method [8], and Deutsch-Mark (DM) method [9] are the most well-known theoretical approaches.

Our group has developed a CSP-ic technique [10], which is used in the present work to calculate the Q_{ion} for the molecules of interest in the present work.

Constructing a complete set of electron scattering cross sections is essential for predicting the performance of fluoronitriles in plasma reactors, industrial gas discharges, gas insulated transmission line (GIL), and gas insulated switchgear (GIS). Only a handful of electron

interaction investigations have been conducted with fluoronitriles, and a literature survey reveals that there are no results for Q_{el} , elastic cross sections, or, Q_T total cross sections.

Number of studies have been undertaken on the gases C_4F_7N and C_3F_5N , with the majority of them focusing on their insulating properties under various environmental conditions. There have been few investigations on microscopic parameters such as ionization cross sections after electron collision. The ionization cross sections (Q_{ion}) is an important quantity in understanding electron avalanche and gas breakdown mechanisms.

A study of the literature shows that results of Q_{el} , elastic cross - section, and Q_T , total cross - section, do not exists, and just a few electron impact investigations with fluoronitriles have been conducted (table 5.1). This is especially the case for information relevant to inelastic processes, such as calculating ionization probabilities.

This is the first attempt at identifying the cross sections for all potential excitations of C_3F_5N . We also want to point out that there have been no earlier research or experimental investigations on the elastic (Q_{el}) or total (Q_T) cross sections of these fluoronitriles. Due to their environmental significance and significance to plasma physics, fluoronitrile molecules are studied in depth here, from IP to 5 keV, to describe the probability of numerous molecular reactions occurring upon electron impact.

5.2 Literature Survey Of Fluoronitrile Compounds

In table 5.1, we discuss all these investigations carried out. Let us review the previous

Studies of the fluoronitriles as follows:

Table 5.1 Previous research addressed the scattering of electrons by fluoronitriles

Molecules	Parameters	Impact Energy (E _i)	References
C ₃ F ₅ N	Q _{ion}	IP-1000eV	[11]
C ₄ F ₇ N	Q _{ion}	IP-1000eV	[11]
	Q _{ion}	IP-2000eV	[9]
	Q _{ion}	IP-100eV	[12]
	Q _{inel} , Q _{ion} , ΣQ _{exc}	IP-5000eV	[13]

5.3 Properties Of Fluoronitriles

Table 5.2 summarises the dielectric strengths and GWP of the molecules studied in relation to SF₆.

Table 5.2 Comparison of the GWP and dielectric strength of SF₆, C₃F₅N and C₄F₇N

Molecule	E _r (rel. SF ₆)	GWP
C ₃ F ₅ N	2 [14]	-
C ₄ F ₇ N	2.74 [9]	2100 [9]
SF ₆	1	23900 [15]

Table 5.3 displays the properties of the fluoronitrile compounds that are used in estimations.

Table 5.3 Target properties of C₃F₅N and C₄F₇N

Molecule	IP(eV)	Polarizability (cm ⁻³)
C ₃ F ₅ N	15.20 [14]	5.72 [16]

C_4F_7N	15.10 [14]	6.82 [16]
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Figure 5.1 depicts a schematic diagram of fluoronitrile compounds.

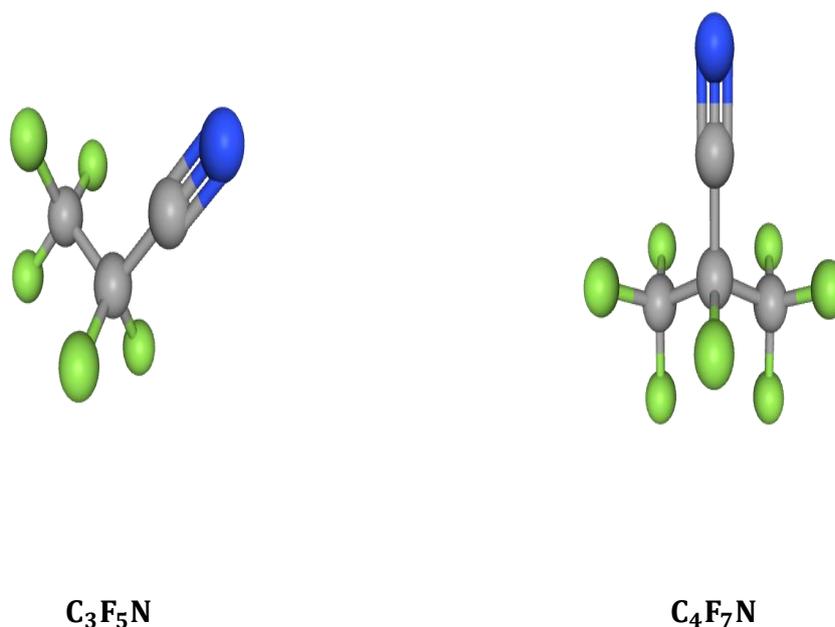


Figure 5.1 Diagrammatic representations of fluoronitrile molecules

(<https://pubchem.ncbi.nlm.nih.gov>)

5.4 Total Cross Sections For Fluoronitriles

We investigated the electron interaction with two plasma-relevant compounds, including C_3F_5N and C_4F_7N . We presented findings together with modest comparisons in two categories:

(A) Inelastic cross sections: Graphical findings from Q_{inel} , Q_{ion} , and ΣQ_{exc} have been reported in this category. Q_{ion} 's ionization cross sections are calculated using the CSP-ic technique.

(B) Total and elastic cross sections: In this category, the graphical outcome of Q_T and Q_{el} has been reported.

5.4.1 Pentafluoropropionitrile

(A) Inelastic processes

As shown in figure 5.2, we will provide inelastic processes for Pentafluoropropionitrile molecules in this subsection and compare them with previous studies.

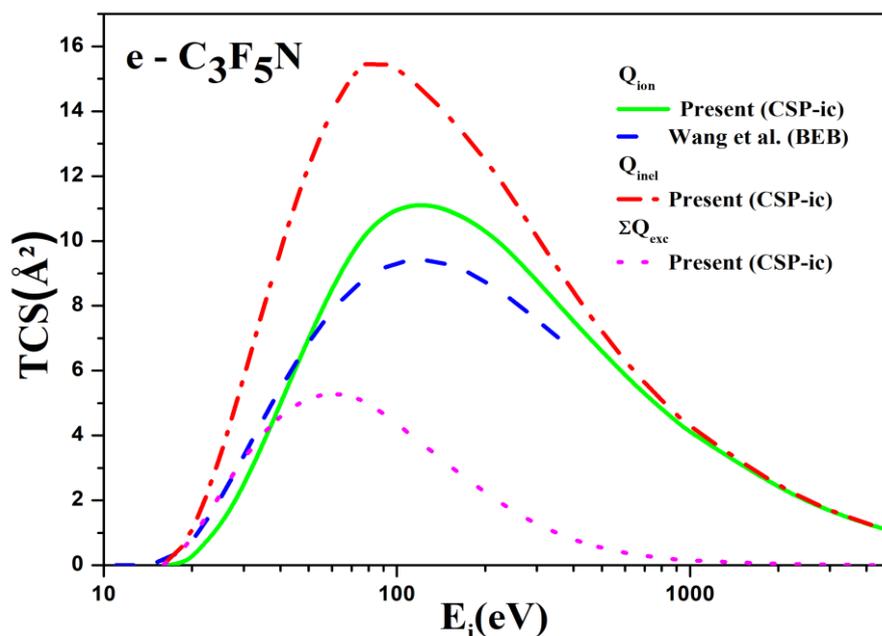


Figure 5.2 Inelastic processes for Pentafluoropropionitrile

Solid: Q_{ion} (Present); Dashed: [11] Q_{ion} (BEB); Dash Dotted: Q_{inel} (Present); Dotted: ΣQ_{exc} (Present)

As can be seen in Figure 5.2 that displays results of $e^- - C_3F_5N$, the upper most Q_{inel} curve depicts total inelastic cross sections. We do not find any previous data of Q_{inel} .

The current Q_{ion} for C_3F_5N matches reasonably well with the BEB estimation of Wang et al. [14] across the whole energy range. Our Q_{ion} values increase more slowly than the BEB data, that reported uncertainty of 10% [17–19]. There is no comparison in the literature to the curve at the bottom, denoted as ΣQ_{exc} , which shows summed total excitation cross sections. ΣQ_{exc} attain peak at 45eV.

(B) Total and elastic cross-sections

In figure 5.3, Q_{el} and Q_T are shown. The two theories applied to find cross-sections match well across the given energy range.

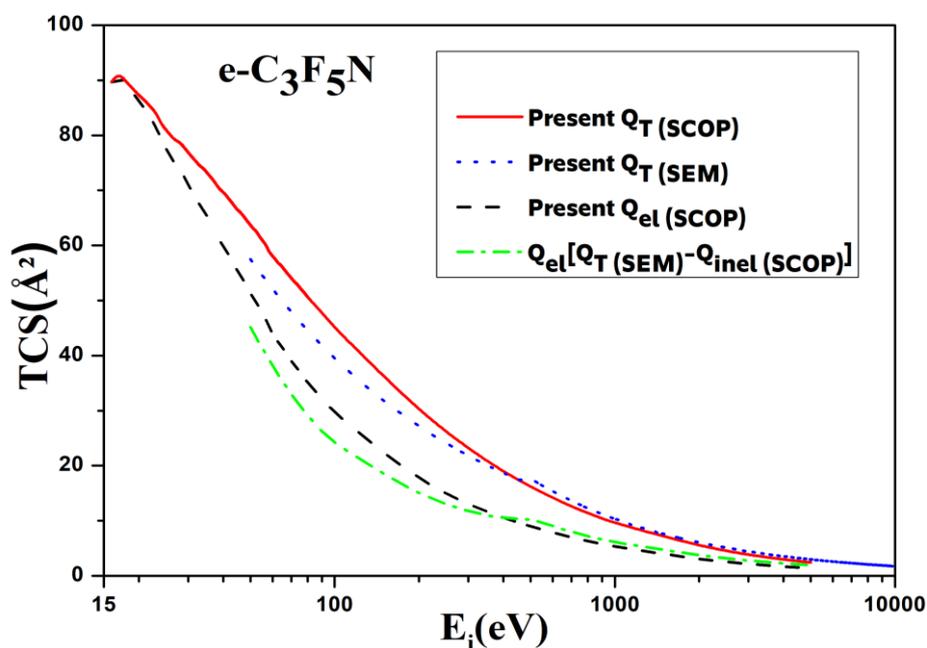


Figure 5.3 Elastic processes for Pentafluoropropionitrile

Solid: Q_T (SCOP) (Present); Dotted: Q_T (SEM) (Present); Dashed: Q_{el} (SCOP) (Present); Dash Dotted: Q_{el} (SEM) (Present)

Table 5.4 lists the computed TCS values for C_3F_5N .

Table 5.4 Total cross-sections (\AA^2) for Pentafluoropropionitrile molecule

E_i (eV)	Q_{ion}	Q_{el}	Q_T
16	0	89.715	89.744
20	0.248	86.141	87.252
30	2.455	71.099	76.891
40	4.975	60.053	69.732

50	6.999	51.414	63.719
60	8.509	44.084	58.07
70	9.598	39.048	54.066
80	10.304	35.111	50.625
90	10.717	32.241	47.884
100	10.959	29.408	44.986
200	10.299	17.235	29.907
300	8.78	12.956	23.1
400	7.536	10.539	18.943
500	6.6	9.016	16.216
600	5.874	7.899	14.21
700	5.292	6.991	12.615
800	4.828	6.338	11.425
900	4.436	5.793	10.436
1000	4.097	5.324	9.593
2000	2.367	2.994	5.401
3000	1.662	2.141	3.823
4000	1.28	1.686	2.977
5000	1.026	1.415	2.446

5.4.2 Heptafluorobutyronitrile

(A) Inelastic Processes

In figure 5.4 inelastic effects for C_4F_7N are shown. That includes Q_{inel} , Q_{ion} and ΣQ_{exc} cross sections.

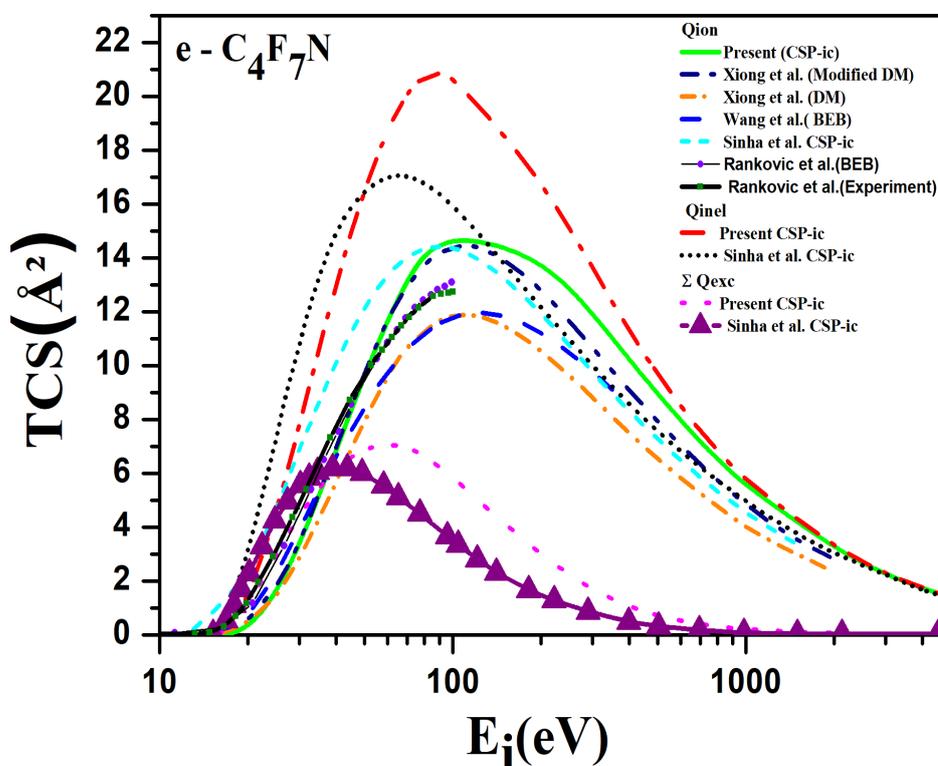


Figure 5.4 Inelastic processes for C_4F_7N

Solid: Q_{ion} (Present); **Dashed:** Wang et al.,2019 Q_{ion} (BEB); **Dash Dot Dotted:** Xiong et al. [9] Q_{ion} (Modified DM); **Short Dashed Dot:** Xiong et al. [9] Q_{ion} (DM); **Short Dashed I:** Sinha et al. [13] Q_{ion} (CSP-ic); **-●-** Rankovic et al. [12](BEB) Q_{ion} ; **-■-** Rankovic et al. [12](Experiment) Q_{ion} ; **Dash Dotted:** Present Q_{inel} (Present); **Short Dotted :** Sinha et al. [13] Q_{inel} (CSP-ic); **Dotted:**Present ΣQ_{exc} ; **-◄-** line: Sinha et al. [13] ΣQ_{exc} (CSP-ic)

Figure 5.4 depicts the electron scattering cross sections for C_4F_7N . The magnitude of the cross sections given here for Q_{inel} and ΣQ_{exc} is larger than that of the results reported by Sinha et al. [13]. Sinha et al.'s [13] Q_{ion} result is slightly left shifted. This difference may be due to the incorporation of nuclear charge into the calculation, which affects both the position and peak value, as Sinha et al. [13] have mentioned. The Modified DM results provided by Xiong et al. [9] are consistent with the present Q_{ion} data. While showing reasonable agreement up to Q_{ion} 's peak, the BEB and DM results are lower for the higher energy levels. In addition to these

findings, the present CSP-ic result is in rather good agreement with the experimental data of the ionisation cross section by Rankovic et al. [12] at lower energies.

(B) Elastic processes

In this subsection, we will demonstrate the current Q_{el} and Q_T for fluoronitrile molecules by using figures 5.5. Figure 5.5 depicts Q_{el} and Q_T . The two theories used to calculate cross-sections agree well over the specified energy range.

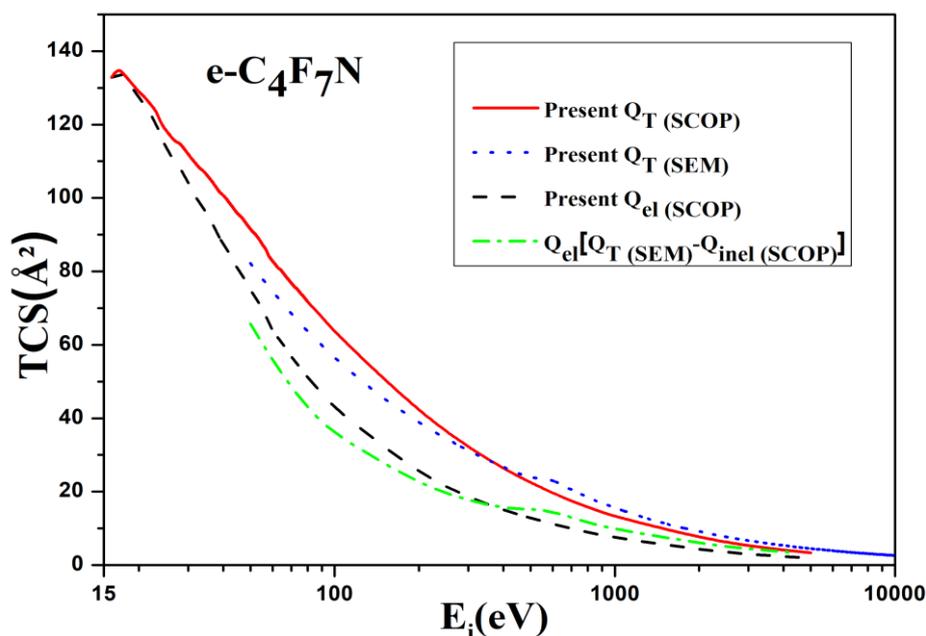


Figure 5.5 Elastic processes for C_4F_7N

Solid: Q_T (SCOP)(Present); Dotted: Q_T (SEM) (Present); Dashed: Q_{el} (SCOP) (Present); Dash Dotted: Q_{el} (SEM) (Present)

Table 5.5 lists the computed TCS values for C_4F_7N .

Here we show SCOP and 2p-SEM results for Q_T in figures 5.3 and 5.5 through the top curves for C_3F_5N and C_4F_7N respectively. Q_T expresses the probability of all electron-induced molecular processes, and it finds use in a variety of modelling methodologies [20,21]. At higher energies, as expected, Q_T decreases as a function of $\frac{1}{E_i}$ in accordance with the Born-Bethe trend. The reported Q_T and Q_{el} using recently developed 2p-SEM method gives excellent

agreement. This is the first effort to describe the Q_{el} and Q_T by two various methods upon electron impact for these key compounds that are crucial to environmental and plasma studies.

Table 5.5 Total cross-sections (\AA^2) for Heptafluorobutyronitrile molecule

E_i (eV)	Q_{ion}	Q_{el}	Q_T
16	0	132.876	132.93
20	0.362	127.318	128.862
30	3.412	104.133	111.957
40	6.859	87.856	100.847
50	9.617	75.1	91.571
60	11.659	64.104	82.805
70	13.127	56.782	76.847
80	13.999	51.041	71.746
90	14.49	46.89	67.771
100	14.95	42.576	63.36
200	14.048	24.691	41.66
300	11.952	18.521	32.13
400	10.24	15.003	26.287
500	8.962	12.817	22.493
600	7.969	11.223	19.71
700	7.168	9.897	17.46
800	6.545	8.977	15.822

900	6.011	8.193	14.445
1000	5.555	7.522	13.274
2000	3.199	4.215	7.461
3000	2.248	3.004	5.272
4000	1.737	2.367	4.112
5000	1.388	1.975	3.371

Using the SCOP approach, we are able to compute Q_{el} in addition to Q_{inel} in the following manner:

$$Q_T(E_i) = Q_{el}(E_i) + Q_{inel}(E_i)$$

The Q_T for fluoronitrile molecules is indicated in these graphs using the top curves. Q_T is a notation that expresses the probability that all electron-induced molecular processes will take place, and it finds use in a variety of methodologies [20,22]. At higher energies, as can be observed, Q_T decreases as a function of $\frac{\ln E_i}{E_i}$ in accordance with the Born-Bethe trend. The Q_{el} for fluoronitrile molecules are represented by the bottom curves in the above two figures. The reported Q_T and Q_{el} using developed 2p-SEM method gives excellent agreement at higher energies. Hence, this is the first effort to describe the Q_{el} and Q_T by two various method upon electron impact for these key compounds that are crucial to environmental and plasma studies.

5.5 Various Correlations: Prediction Of Polarizability And Dielectric Constant

The SCOP technique discusses how the interactions between electrons and charged cloud of the molecule takes place and allows for an estimation of the possibility of various electron-assisted chemical processes. Table 5.6 shows the polarizability and other properties of C_3F_5N , C_4F_7N , and perfluoroketone (PFK) ($C_xF_{2x}O$, $x=5-6$) [23] molecules that are either available in

the literature or are expected to be studied in this work. The data and correlations may be used to calculate the polarizability of fluoroketone and fluoronitrile. The total number of electrons determines the size of the molecular cloud (n_e).

Table 5.6 Molecular properties and predicted α

Target	n_e	Ionization Potential (eV)	Polarizability (10^{-24}cm^3)		
			Present	Estimated	Found at www.chemspider.com
$\text{C}_3\text{F}_5\text{N}$	70	15.20 [11]	5.72 [16]	5.97	6.6 (deviation 10%)
$\text{C}_4\text{F}_7\text{N}$	94	15.10[12]	6.82 [16]	7.60	8.5 (deviation 11%)
$\text{C}_5\text{F}_{10}\text{O}$	128	12.02 [24]	8.83 [25]	9.84	10.6 (deviation 7.1%)
$\text{C}_6\text{F}_{12}\text{O}$	152	11.41 [26]	11.44 [27]	12.54	12.6 (deviation 0.4 %)

In figure 5.6 the behaviour of Q_{ion} (max) with respect to number of electrons of molecules is shown.

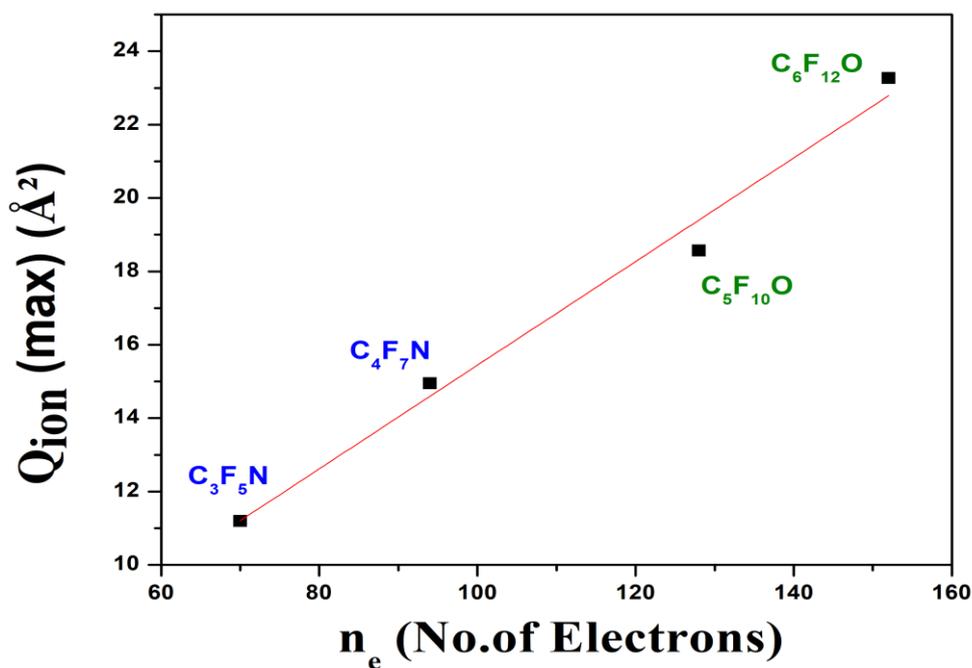


Figure 5.6 Variation of $Q_{\text{ion}}(\text{max})$ with n_e

The size of the molecular cloud, defined by the number of electrons, n_e , is significant for the peak of Q_{ion} of each molecule. When the charge cloud expands in size, the orders of magnitude of impact energy-specific cross sections increase. Q_{ion} depends on the initial ionization potential, which does not vary considerably for extremely big molecules, in addition to the target cloud size (table 5.6). As a result, a linear connection between $Q_{\text{ion}}(\text{max})$ and n_e is seen (figure 5.6).

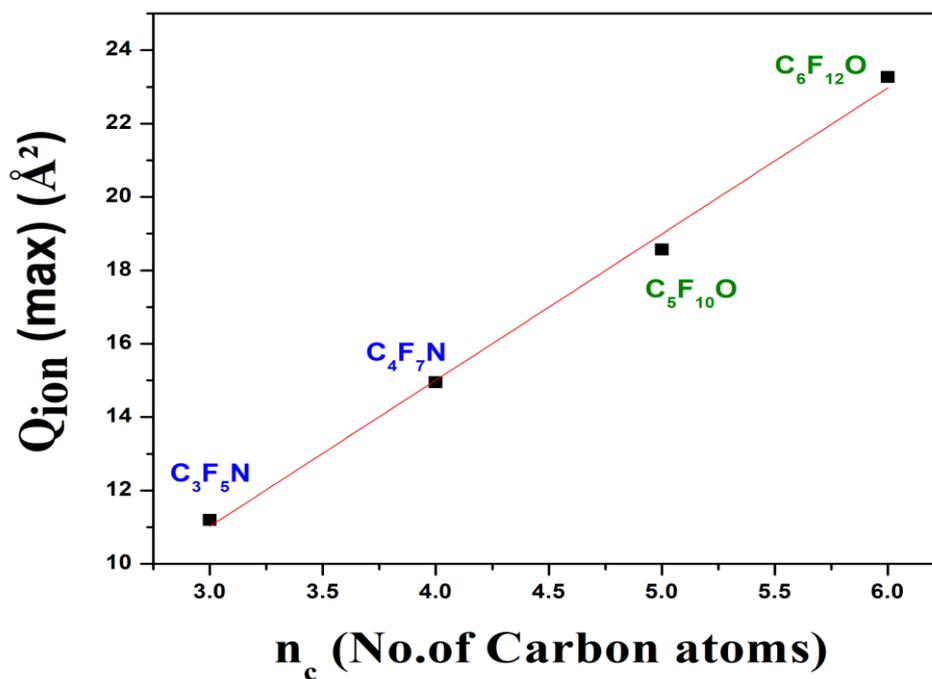


Figure 5.7 Variation of $Q_{\text{ion}}(\text{max})$ with n_c

Figure 5.7 shows a similar trend for $Q_{\text{ion}}(\text{max})$ with the number of C (carbon) atoms present in the target for fluoroketones and fluoronitriles. These relationships, together with some simple extrapolation, can be used to predict the $Q_{\text{ion}}(\text{max})$ of such large molecules.

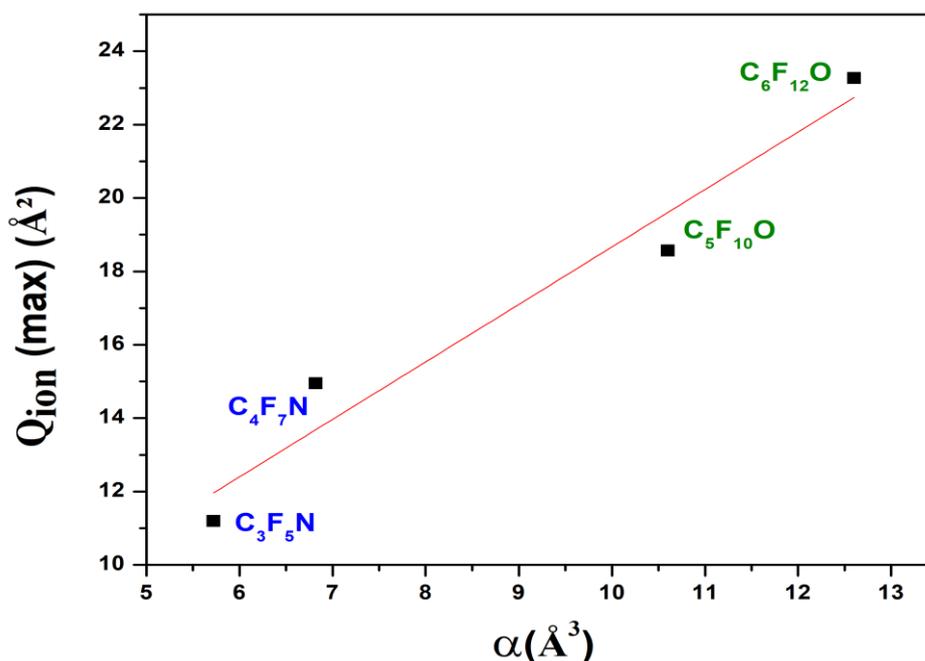


Figure 5.8 Variation of $Q_{\text{ion}}(\text{max})$ with α

In figure 5.9, we established a linear relation between $Q_{\text{ion}}(\text{max})$ and ϵ . With the help of this, we can estimate the dielectric constant for the series of molecules from Q_{ion} values. We can also predict Q_{ion} from dielectric constant. Our findings confirm the linear relationship between $Q_{\text{ion}}(\text{max})$ and polarizability, as reported by Bart et al. [28], through which we can predict polarizability for similar compounds like $\text{C}_3\text{F}_5\text{N}$, $\text{C}_4\text{F}_7\text{N}$, $\text{C}_5\text{F}_{10}\text{O}$ and $\text{C}_6\text{F}_{12}\text{O}$. In table 5.6, we can see an excellent matching between the predicted and the computed values, up to 95.18% for $\text{C}_3\text{F}_5\text{N}$, 90% for $\text{C}_4\text{F}_7\text{N}$ and for, $\text{C}_5\text{F}_{10}\text{O}$, $\text{C}_6\text{F}_{12}\text{O}$ it is about 92.80% and 99.50% respectively. Table 5.6 shows various properties including polarizability of $\text{C}_3\text{F}_5\text{N}$, $\text{C}_4\text{F}_7\text{N}$, and perfluoroketone (PFK) ($\text{C}_x\text{F}_{2x}\text{O}$, $x=5-6$) [23] molecules. The data and correlations can be used to predict the polarizability of fluoroketones and fluoronitriles. The total number of electrons (n_e) decides the dimension of the molecular cloud

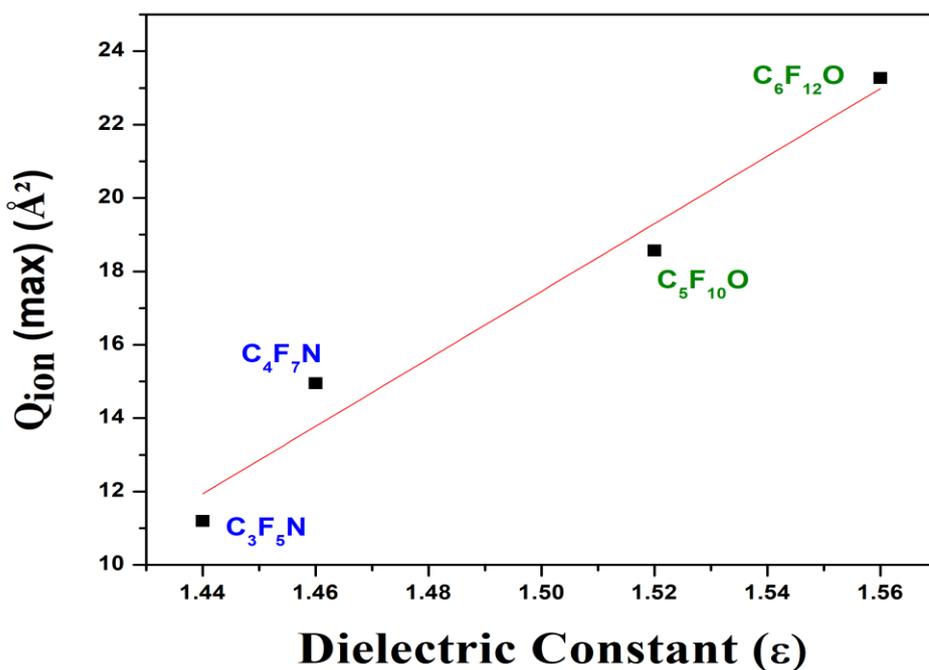


Figure 5.9 Variation of $Q_{ion}(max)$ with ϵ

In table 5.7, we report number density and computed dielectric constant using polarizability for C_3F_5N and C_4F_7N .

Table 5.7 Calculated number density N and dielectric constant ϵ

Target	Polarizability, α ($10^{-24}cm^{-3}$)	Density of material, ρ g/cm^3	Molar mass, M g/mol	Calculated Number Density, N $molecules/cm^3$	Calculated Dielectric Constant, ϵ
C_3F_5N	5.72 [16]	1.5 [29]	145.03 [29]	$6.2 \cdot 10^{21}$	1.52
C_4F_7N	6.82 [16]	1.5 ± 0.1 [29]	195.03 [29]	$4.6 \cdot 10^{21}$	1.45

The Clausius-Mossotti equation yields a linear connection between polarizability and dielectric constant. We may assume a linear relationship between $Q_{ion}(max)$ and the dielectric constant since there is a linear relationship between $Q_{ion}(max)$ and polarizability [28], as shown in

figure 5.8. Figure 5.9 depicts this property for the molecules under consideration. Consequently, the present research of cross section computation upon electron impact can aid in predicting dielectric constant for any electrically conductive substance.

According to J. C. Devins' research, fluoro-nitrile organic gases such as C_3F_5N and C_4F_7N can have double the electric strength of SF_6 [30]. When compared to pure epoxy resin, the electrical characteristics of a composite material consisting of C_3F_5N and epoxy resin demonstrated better dielectric strength and thermal stability. In the design and optimisation of this composite material, the dielectric constant of C_3F_5N was employed as a crucial parameter [31].

The dielectric characteristics of C_4F_7N suggest that it might be used as a high-performance insulating gas in power equipment. The dielectric constant was found to be much larger than that of SF_6 , a commonly used insulating gas, indicating that C_4F_7N might be a potential option for use in power equipment [32,33].

5.6 Chapter Summary

We report quantified probabilities of various electron assisted molecular processes for applied fluoronitriles C_3F_5N and C_4F_7N for wide impact energies (IP to 5 keV). We performed calculations for Q_{el} , Q_{inel} , and Q_T using the SCOP formalism, obtained Q_{ion} and $\Sigma\Sigma Q_{exc}$ through CSP-ic method and displayed results graphically in figures 5.2 – 5.5 along with available comparison. Present Q_{ion} agrees reasonably well with adjusted DM data [9] and BEB [11] for these compounds (figure 5.2 and 5.3). Since there is no previous data on Q_{el} and Q_T we have compared present Q_{el} and Q_T computed through SCOP with newly developed 2 parameter semi empirical method (2p-SEM) in figure 5.4 and 5.5. This new method is applicable for large molecules ($55 < Z < 95$) and over a wide energy range $50 \text{ eV} < E_i < 5000 \text{ eV}$. We find excellent agreement throughout the energy range of investigation for Q_{el} and Q_T .

We also verified the sensitivity of Q_{ion} to size of the molecule (n_e) as well as total number of carbon atoms (n_c) and observed a linear relationship $Q_{ion}(\text{max})$ with them (figure 5.6 and 5.7). We found a linear correlation between $Q_{ion}(\text{max})$ and polarizability shown in figure 5.8 as expected by Bart et al. [34]. When we compared our predictions for the dipole polarizability of C_3F_5N , C_4F_7N , C_2F_4O , $C_5F_{10}O$, and $C_6F_{12}O$ to those computed using

www.chemspider.com, we found that our predictions were in excellent agreement with those of the latter as mentioned in table 5.6.

These two significant environmental and plasma-relevant compounds, C_3F_5N and C_4F_7N , have an exceptionally greater dielectric strength and lower GWP, making them appealing for commercial prospects and effective alternative for SF_6 . For these applied molecules we also found number density N and reported dielectric constant ϵ using molecular polarizability and observed a linear relation between Q_{ion} (max) and the dielectric constant of the system as shown in figure 5.9. Thus the current study of cross section calculations upon electron impact can help predict dielectric constant for any materials of electrical applications.

While this work is the maiden report of ΣQ_{exc} and Q_{inel} for C_3F_5N , it is the first study of Q_{el} and Q_T for both C_3F_5N and C_4F_7N using SCOP as well 2p-SEM methods. Reported theoretical results in this work may encourage experimentalists to embark on similar projects.

5.7 Bibliography

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